

X3-Class HiPerFET™ **Power MOSFET**

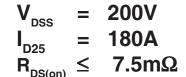
IXFT180N20X3HV **IXFH180N20X3**

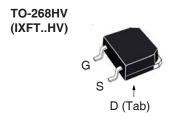
N-Channel Enhancement Mode Avalanche Rated

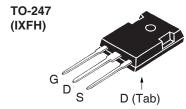


Symbol	Test Conditions	Maximum Ratings	
V _{DSS}	$T_J = 25^{\circ}C$ to $150^{\circ}C$	200	V
V _{DGR}	$T_{_{\mathrm{J}}}$ = 25°C to 150°C, $R_{_{\mathrm{GS}}}$ = 1M Ω	200	V
V _{GSS}	Continuous	±20	V
V _{GSM}	Transient	±30	V
I _{D25}	T _C = 25°C	180	A
L(RMS)	External Lead Current Limit	160	Α
I _{DM}	$T_{\rm C} = 25^{\circ}$ C, Pulse Width Limited by $T_{\rm JM}$	320	Α
I _A	T _C = 25°C	90	A
E _{AS}	$T_{c} = 25^{\circ}C$	2.2	J
dv/dt	$I_{S} \leq I_{DM}, V_{DD} \leq V_{DSS}, T_{J} \leq 150^{\circ}C$	20	V/ns
P _D	T _C = 25°C	735	W
T _J		-55 +150	°C
T_{JM}		150	°C
T _{stg}		-55 +150	°C
T _L	Maximum Lead Temperature for Soldering	300	°C
T _{SOLD}	1.6 mm (0.062in.) from Case for 10s	260	°C
M _d	Mounting Torque (TO-247)	1.13 / 10	Nm/lb.in
Weight	TO-268HV	4	g
	TO-247	6	g

Symbol Test Conditions Character (T _J = 25°C, Unless Otherwise Specified) Min.		teristic Values Typ. Max.		
BV _{DSS}	$V_{GS} = 0V, I_D = 1mA$	200		V
$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 4mA$	2.5		4.5 V
GSS	$V_{GS} = \pm 20V, V_{DS} = 0V$			±100 nA
l _{DSS}	$V_{DS} = V_{DSS}, V_{GS} = 0V$ $T_{J} = 125^{\circ}C$			25 μA 1 mA
R _{DS(on)}	$V_{GS} = 10V, I_{D} = 0.5 \bullet I_{D25}, Note 1$		6.3	7.5 mΩ







G = Gate	D	=	Drain
S = Source	Tab	=	Drain

Features

- International Standard Packages
- Low $R_{DS(ON)}$ and Q_G Avalanche Rated
- Low Package Inductance

Advantages

- High Power Density
- Easy to Mount
- Space Savings

Applications

- Switch-Mode and Resonant-Mode **Power Supplies**
- DC-DC Converters
- PFC Circuits
- AC and DC Motor Drives
- · Robotics and Servo Controls



Symbol Test Conditions Char		acteristic Values		
$(T_{J} = 25^{\circ}C,$	Unless Otherwise Specified)	Min.	Тур.	Max
g _{fs}	$V_{DS} = 10V, I_{D} = 60A, Note 1$	70	120	S
R _{Gi}	Gate Input Resistance		1.5	Ω
C _{iss}			10.3	nF
C _{oss}	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		1.7	nF
C _{rss}			5.2	pF
	Effective Output Capacitance			
$C_{o(er)}$	Energy related $\int V_{GS} = 0V$		810	pF
$C_{o(tr)}$	Time related $\int V_{DS}^{GS} = 0.8 \cdot V_{DSS}$		2540	pF
t _{d(on)}	Resistive Switching Times		30	ns
t, ($V_{GS} = 10V$, $V_{DS} = 0.5 \cdot V_{DSS}$, $I_{D} = 0.5 \cdot I_{D25}$		28	ns
t _{d(off)}	$R_{\rm GS} = 10V$, $V_{\rm DS} = 0.3 \cdot V_{\rm DSS}$, $I_{\rm D} = 0.3 \cdot I_{\rm D25}$ $R_{\rm G} = 5\Omega$ (External)		100	ns
t,)	n _G = 352 (External)		12	ns
$Q_{g(on)}$			154	nC
Q _{gs}	$V_{GS} = 10V$, $V_{DS} = 0.5 \cdot V_{DSS}$, $I_D = 0.5 \cdot I_{D25}$		50	nC
			45	nC
R _{thJC}				0.17 °C/W
R _{thCS}	TO-247		0.21	°C/W

Source-Drain Diode

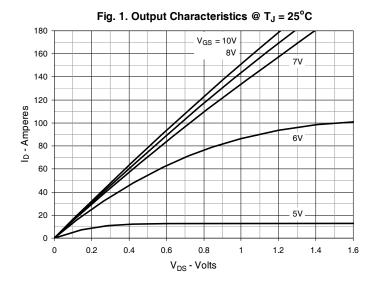
		Chara Min.	acteristic Values Typ. Max		
I _s	$V_{GS} = 0V$			180	Α
I _{SM}	Repetitive, pulse Width Limited by $T_{_{\rm JM}}$			720	Α
V _{SD}	$I_F = 100A$, $V_{GS} = 0V$, Note 1			1.4	V
$\left\{ egin{array}{c} \mathbf{t}_{rr} \\ \mathbf{Q}_{RM} \\ \mathbf{I}_{RM} \end{array} \right\}$	$I_F = 90A$, $-di/dt = 100A/\mu s$ $V_R = 100V$		120 550 9		ns nC A

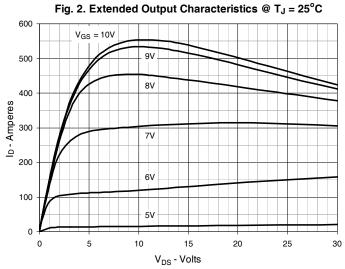
Note 1. Pulse test, $t \le 300\mu s$, duty cycle, $d \le 2\%$.

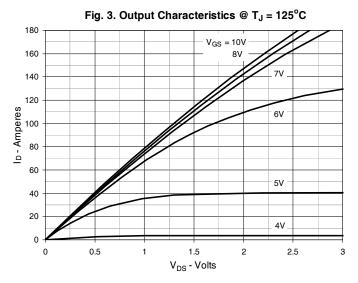
PRELIMINARY TECHNICAL INFORMATION

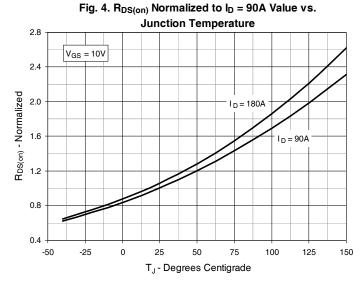
The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

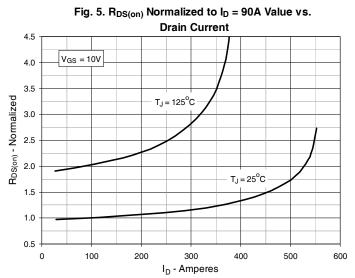


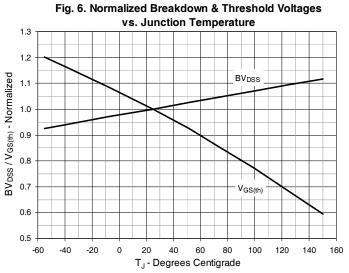




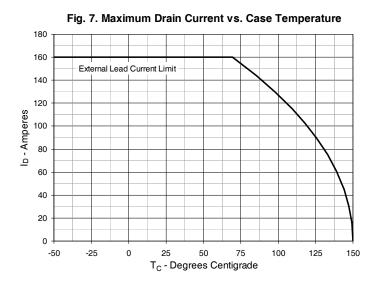


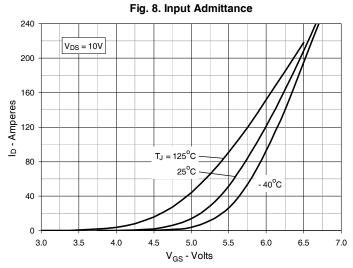


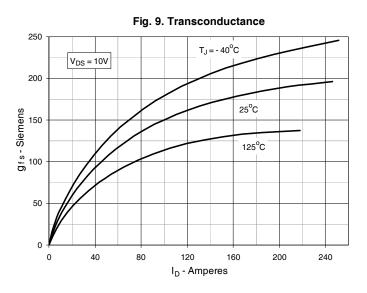


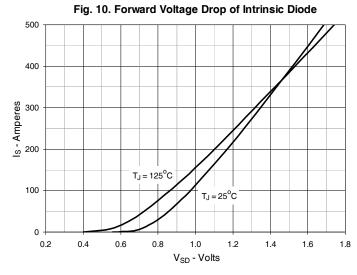


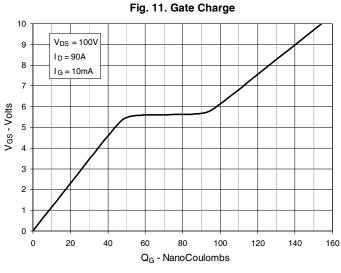


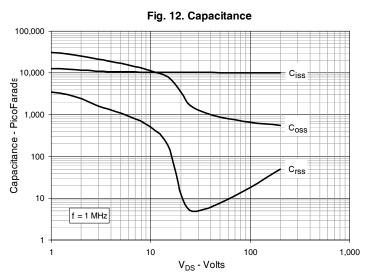






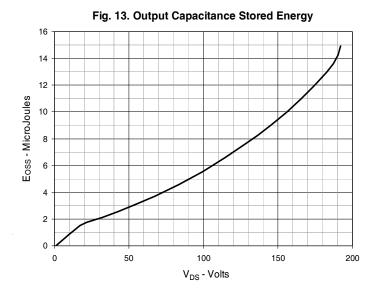






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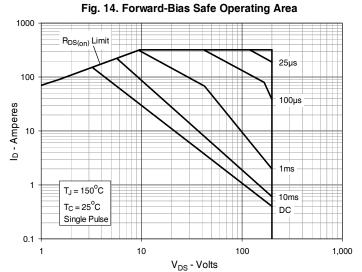
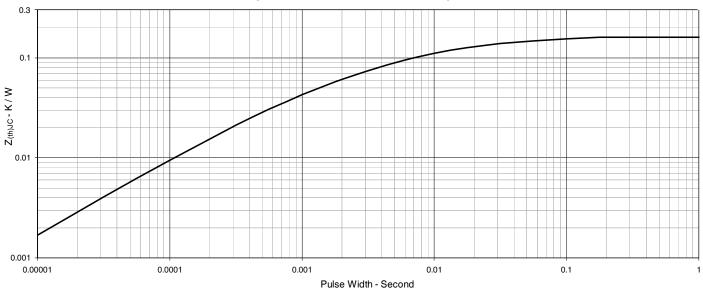
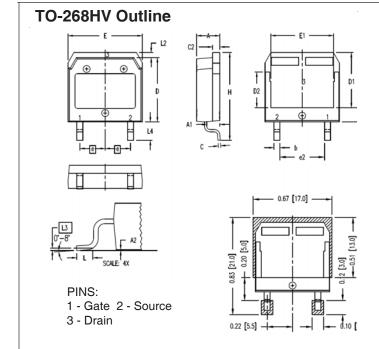


Fig. 15. Maximum Transient Thermal Impedance







SYM	INCHES		MILLIMETER	
STM	MIN	MAX	MIN	MAX
Α	.193	.201	4.90	5.10
A1	.106	.114	2.70	2.90
A2	.001	.010	0.02	0.25
Ь	.045	.057	1.15	1.45
C C2	.016	.026	0.40	0.65
C2	.057	.063	1.45	1.60
D	.543	.551	13.80	14.00
D1	.465	.476	11.80	12.10
D2	.295	.307	7.50	7.80
D3	.114	.126	2.90	3.20
E	.624	.632	15.85	16.05
E1	.524	.535	13.30	13.60
е	.215	BSC	5.45 BSC	
(e2)	.374	.386	9.50	9.80
Η	.736	.752	18.70	19.10
L	.067	.079	1.70	2.00
L2	.039	.045	1.00	1.15
L3	.010	BSC	0.25 BSC	
	.150	.161	3.80	4 .10

